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December 2014

FCH077N65F

N-Channel SuperFET® II FRFET® MOSFET

650 V, 54 A, 77 mΩ

Features

- 700 V @ T_J = 150°C
- Typ. $R_{DS(on)} = 68 \text{ m}\Omega$
- Ultra Low Gate Charge (Typ. Q_q = 126 nC)
- Low Effective Output Capacitance (Typ. C_{oss(eff.)} = 693 pF)
- · 100% Avalanche Tested
- · RoHS Compliant

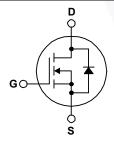
Applications

- LCD / LED / PDP TV Telecom / Server Power Supplies
- · Solar Inverter
- · AC DC Power Supply

Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SuperFET II FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter		FCH077N65F_F155	Unit
V _{DSS}	Drain to Source Voltage			650	V
	Cata ta Causaa Malta sa	- DC		±20	V
V _{GSS} Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V	
	Desir Comment	- Continuous (T _C = 25°C)		54	^
	- Continuous (T _C = 100°C)		32	Α	
I _{DM}	Drain Current	- Pulsed	(Note 1)	162	Α
E _{AS}	Single Pulsed Avalanche Ene	rgy	(Note 2)	1128	mJ
I _{AR}	Avalanche Current		(Note 1)	11	Α
E _{AR}	Repetitive Avalanche Energy		(Note 1)	4.81	mJ
dv/dt	MOSFET dv/dt			100	1//20
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	50	V/ns
D	Dower Discipation	(T _C = 25°C)		481	W
P _D Power Dissipation	Power Dissipation	- Derate Above 25°C		3.85	W/°C
T _J , T _{STG}	Operating and Storage Tempe	erature Range		-55 to +150	°C
T _L	Maximum Lead Temperature 1/8" from Case for 5 Seconds	•		300	°C

Thermal Characteristics

Symbol	Parameter	FCH077N65F_F155	Unit
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.26	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max. 40		C/VV

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCH077N65F_F155	FCH077N65F	TO-247 G03	Tube	N/A	N/A	30 units

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Off Charac	cteristics					
D\/	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	650	-	-	V
BV _{DSS}	Dialii to Source Breakdown voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 150^{\circ}\text{C}$	700	-	-	V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	I _D = 10 mA, Referenced to 25°C	-	0.72	-	V/°C
1	Zero Gate Voltage Drain Current	V _{DS} = 650 V, V _{GS} = 0 V	-	-	10	μА
I _{DSS}	Zero Gate voltage Drain Current	$V_{DS} = 520 \text{ V}, V_{GS} = 0 \text{ V}, T_{C} = 125 ^{\circ}\text{C}$	-	144	-	μΑ
I _{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±100	nA

On Characteristics

V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 5.4$ mA	3	-	5	V
R _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 27 \text{ A}$	-	68	77	mΩ
9 _{FS}	Forward Transconductance	$V_{DS} = 20 \text{ V}, I_{D} = 27 \text{ A}$	-	42	-	S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 400 V V 0 V	-	5345	7109	pF
C _{oss}	Output Capacitance	V _{DS} = 100 V, V _{GS} = 0 V, f = 1 MHz		165	220	pF
C _{rss}	Reverse Transfer Capacitance	1 – 1 1011 12	-	8.0	-	pF
Coss	Output Capacitance	V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz	- \	97	-	pF
C _{oss(eff.)}	Effective Output Capacitance	V _{DS} = 0 V to 400 V, V _{GS} = 0 V	- \	693	-	pF
Q _{g(tot)}	Total Gate Charge at 10V	V _{DS} = 380 V, I _D = 27 A,	-	126	164	nC
Q_{gs}	Gate to Source Gate Charge	V _{GS} = 10 V	-	28	-	nC
Q_{gd}	Gate to Drain "Miller" Charge	(Note 4)	-	53	-	nC
ESR	Equivalent Series Resistance	f = 1 MHz	-	0.7	-	Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		-	40	90	ns
t _r		$V_{DD} = 380 \text{ V}, I_D = 27 \text{ A},$	-/	35	80	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_g = 4.7 Ω	-	113	236	ns
t _f	Turn-Off Fall Time	(Note 4)	/ -	5	20	ns

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain to Source Diod	Maximum Continuous Drain to Source Diode Forward Current			54	Α
I_{SM}	Maximum Pulsed Drain to Source Diode Forward Current			-	162	Α
V_{SD}	Drain to Source Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{SD} = 27 \text{ A}$	-	-	1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _{SD} = 27 A,	-	163	- ,	ns
Q _{rr}	Reverse Recovery Charge	$dI_F/dt = 100 A/\mu s$	-	0.9	-	μС

Notes:

- 1. Repetitive rating: pulse width limited by maximum junction temperature.
- 2. I_{AS} = 11 A, R_G = 25 Ω , Starting T_J = 25°C.
- 3. I $_{SD} \leq$ 27 A, di/dt \leq 200 A/µs, V $_{DD} \leq$ 380 V, Starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

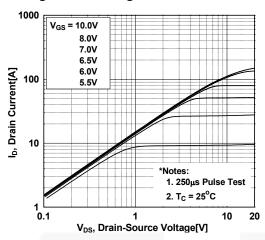


Figure 3. On-Resistance Variation vs.
Drain Current and Gate Voltage

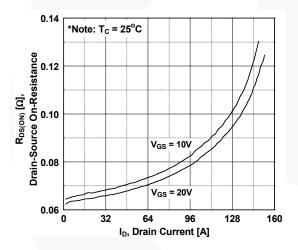


Figure 5. Capacitance Characteristics

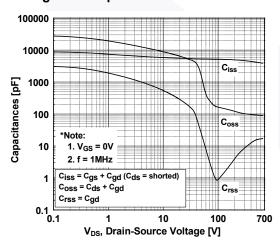


Figure 2. Transfer Characteristics

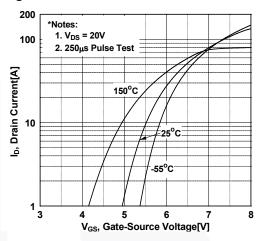


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

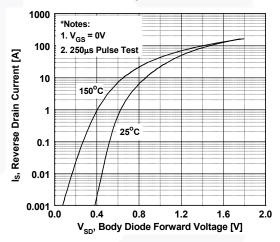
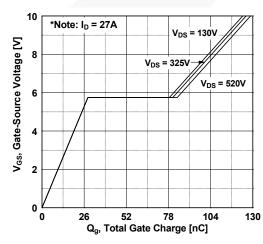


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

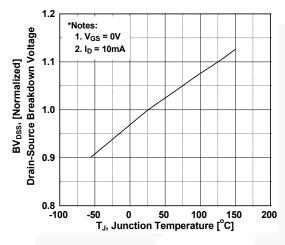


Figure 9. Maximum Safe Operating Area

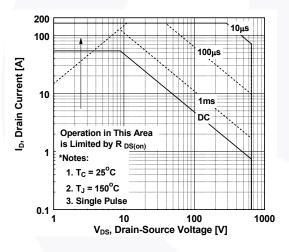


Figure 11. Eoss vs. Drain to Source Voltage

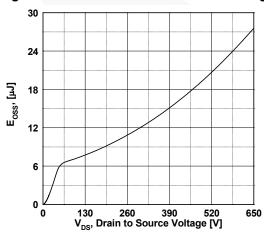


Figure 8. On-Resistance Variation vs. Temperature

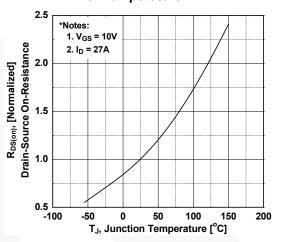
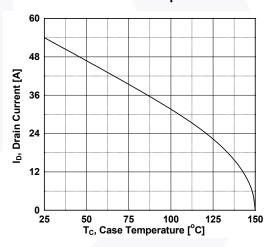
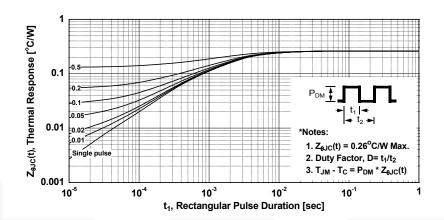


Figure 10. Maximum Drain Current vs. Case Temperature



Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



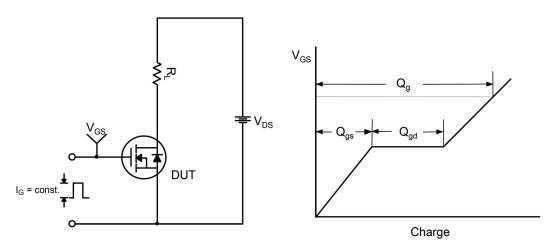


Figure 13. Gate Charge Test Circuit & Waveform

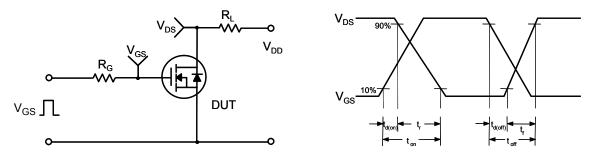


Figure 14. Resistive Switching Test Circuit & Waveforms

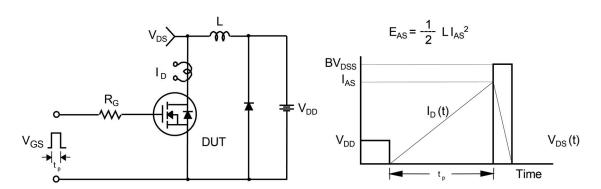
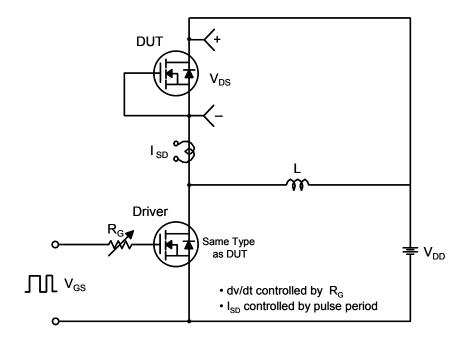


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms



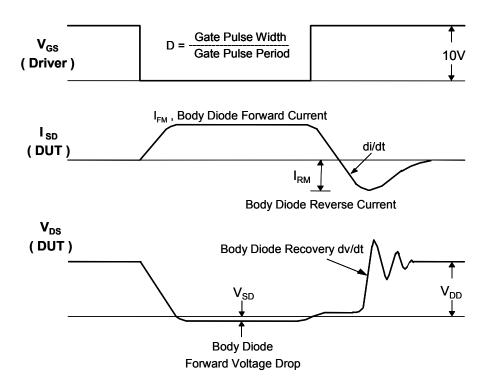
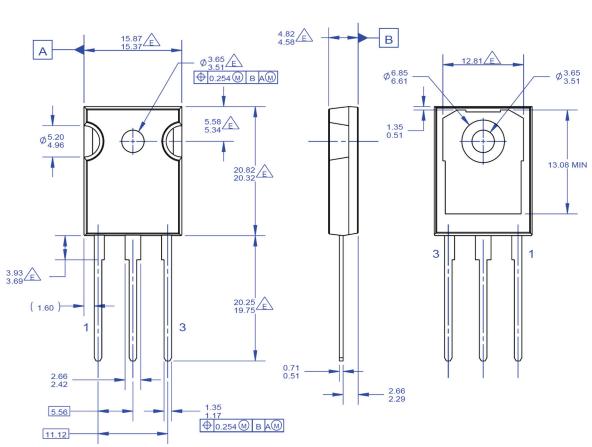


Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions



NOTES: UNLESS OTHERWISE SPECIFIED

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Figure 17. TO-247, Molded, 3-Lead, Jedec AB Long Leads

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